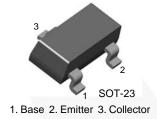


November 2014

# BC807 / BC808 PNP Epitaxial Silicon Transistor

### **Features**

- Switching and Amplifier Applications
- Suitable for AF-Driver Stages and Low Power Output Stages
- Complement to BC817 / BC818



### **Ordering Information**

Part Number	Marking	Package	Packing Method
BC80716MTF	9FA	SOT-23 3L	Tape and Reel
BC80725MTF	9FB	SOT-23 3L	Tape and Reel
BC80740MTF	9FC	SOT-23 3L	Tape and Reel
BC80840MTF	9GC	SOT-23 3L	Tape and Reel

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}\text{C}$  unless otherwise noted.

Symbol	Parameter	Value	Unit	
V <sub>CES</sub> Collector-Emitter Vo	Callegae Freitten Valtege	BC807	-50	V
	Collector-Emitter voltage	BC808	-30	V
V <sub>CEO</sub> Collec	Heaten Freitten Veltere	BC807	-45	V
	Collector-Emitter Voltage	BC808	-25	V
V <sub>EBO</sub>	O Emitter-Base Voltage		-5	V
I <sub>C</sub>	Collector Current (DC)		-800	mA
T <sub>J</sub>	Junction Temperature		150	°C
T <sub>STG</sub>	Storage Temperature		-65 to +150	°C

1

### Thermal Characteristics(1)

Values are at  $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value	Unit
В	Power Dissipation	310	mW
P <sub>D</sub>	Derate Above 25°C	2.48	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	403	°C/W

### Note:

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

### **Electrical Characteristics**

Values are at  $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter		Conditions	Min.	Тур.	Max.	Unit
BVoco	Collector-Emitter Breakdown Voltage	BC807	$I_C = -10 \text{ mA}, I_B = 0$	-45			V
		BC808		-25			
D\/	Collector-Emitter Breakdown		0.4 m / 1/ 0	-50			V
BV <sub>CES</sub>	Voltage	BC808	$I_C = -0.1 \text{ mA}, V_{BE} = 0$	-30			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage		$I_E = -0.1 \text{ mA}, I_C = 0$	-5			V
I <sub>CES</sub>	Collector Cut-Off Current		$V_{CE} = -25 \text{ V}, V_{BE} = 0$			-100	nA
I <sub>EBO</sub>	Emitter Cut-Off Current		$V_{EB} = -4 \text{ V}, I_{C} = 0$			-100	nA
h <sub>FE1</sub>	h <sub>FE1</sub> DC Current Gain		$V_{CE} = -1 \text{ V}, I_{C} = -100 \text{ mA}$	100		630	
h <sub>FE2</sub>			$V_{CE} = -1 \text{ V}, I_{C} = -300 \text{ mA}$	60			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage		$I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$			-0.7	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage		$V_{CE} = -1 \text{ V}, I_{C} = -300 \text{ mA}$			-1.2	V
f <sub>T</sub>	Current Gain Bandwidth Product		$V_{CE} = -5 \text{ V, } I_{C} = -10 \text{ mA,}$ f = 50 MHz		100		MHz
C <sub>ob</sub>	Output Capacitance		V <sub>CB</sub> = -10 V, f = 1 MHz			12	pF

### h<sub>FE</sub> Classification

Classification	16	25	40
h <sub>FE1</sub>	100 ~ 250	160 ~ 400	250 ~ 630
h <sub>FE2</sub>	60 ~	100 ~	170 ~

### **Typical Performance Characteristics**

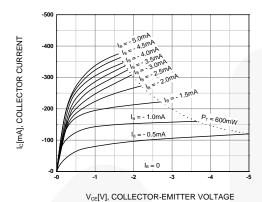


Figure 1. Static Characteristic

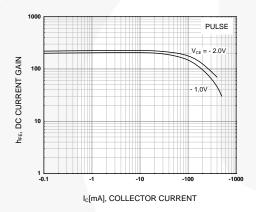


Figure 3. DC Current Gain

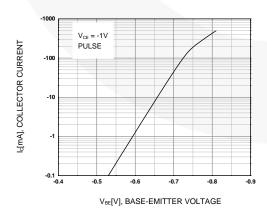


Figure 5. Base-Emitter On Voltage

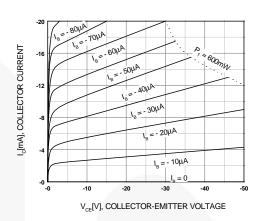


Figure 2. Static Characteristic

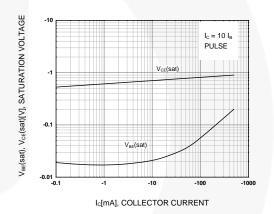
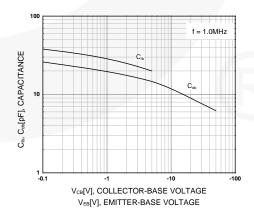


Figure 4. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage



**Figure 6. Input Output Capacitance** 

### Typical Performance Characteristics (Continued)

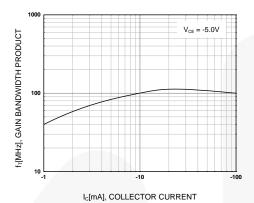


Figure 7. Current Gain Bandwidth Product

### **Physical Dimensions** 0.95 2.92±0.20 3 1.40 1.30+0.20 2.20 2 0.60 0.37 (0.29) -0.95 ⊕ 0.20M A B 1.00 1.90 1.90 LAND PATTERN RECOMMENDATION SEE DETAIL A -1.20 MAX 0.10 (0.93) ○ 0.10 M C С 2.40±0.30 NOTES: UNLESS OTHERWISE SPECIFIED

**GAGE PLANE** 0.23 0.25 0.20 MIN **PLANE** (0.55)

- A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
- D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 1994.
- SEATING E) DRAWING FILE NAME: MA03DREV10

**DETAIL A** SCALE: 2X

Figure 8. 3-LEAD, SOT23, JEDEC TO-236, LOW PROFILE





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